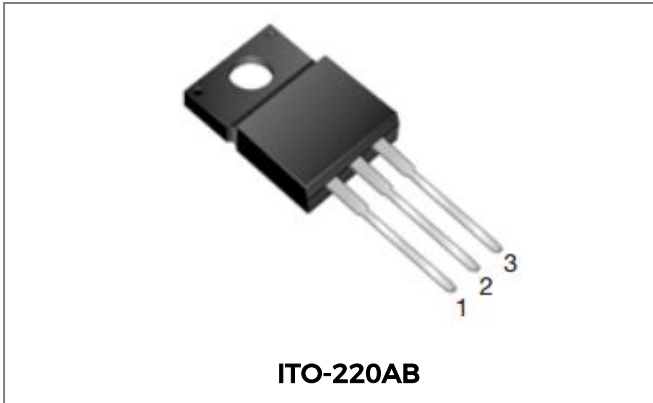


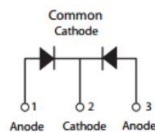
STF40300C SCHOTTKY RECTIFIER



Features

- 175 °C T_j operation
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Terminals finish: Tin Lead-free plated
- Trench MOS Schottky technology
- This is a Pb - Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	-	300	V
Average Rectified Forward Current	$I_{F(AV)}$	$T_c=101^{\circ}\text{C}$, In DC	20(Per Leg) 40(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I_{FSM}	8.3ms, Half Sine pulse, $T_c=25^{\circ}\text{C}$	235	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop (Per Leg)*	V_{F1}	@ 20A, Pulse, $T_j = 25^{\circ}\text{C}$	0.89	0.92	V
	V_{F2}	@ 20A, Pulse, $T_j = 125^{\circ}\text{C}$	0.76	0.82	V
Reverse Current(Per Leg)*	I_{R1}	@ V_R = rated V_R , $T_j = 25^{\circ}\text{C}$	0.4	100	uA
	I_{R2}	@ V_R = rated V_R , $T_j = 125^{\circ}\text{C}$	0.09	10	mA
Junction Capacitance	C_T	@ $V_R = 5\text{V}$, $T_c = 25^{\circ}\text{C}$, $f_{SIG} = 1\text{MHz}$	310	-	pF

* Pulse width < 300 μs , duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	in DC forward mode	-55 to +175	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	-	-55 to +175	$^{\circ}\text{C}$
Typical Thermal Resistance Junction to Case(Per Leg)	$R_{\theta JC}$	DC operation	4	$^{\circ}\text{C/W}$
Approximate Weight	wt	-	2	g
Case Style	ITO-220AB			

Ratings and Characteristics Curves

Figure1
Typical Forward Characteristics

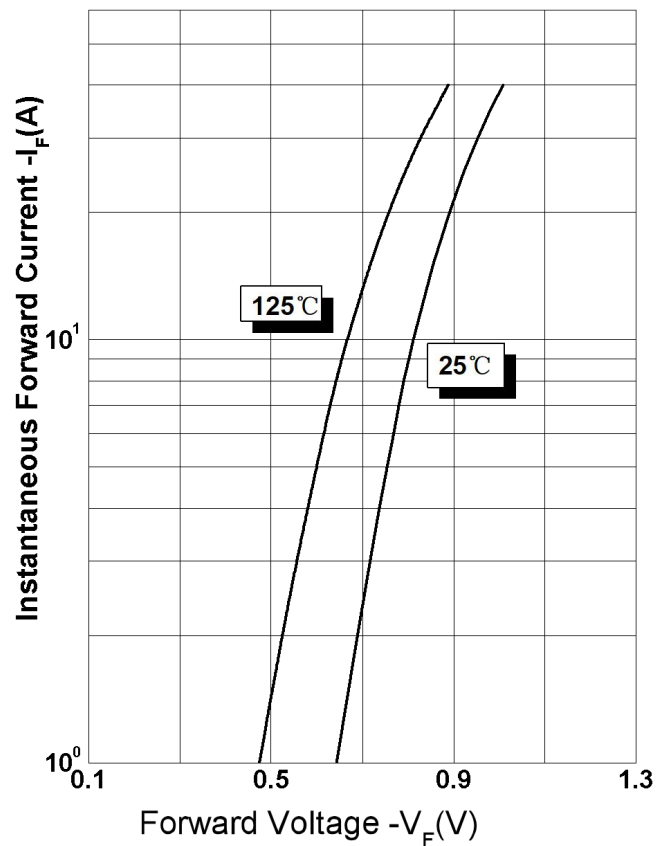


Figure 2
Typical Reverse Characteristics

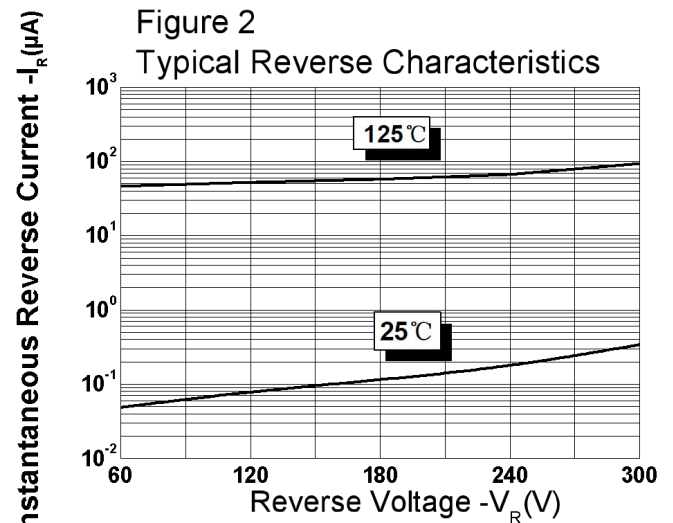
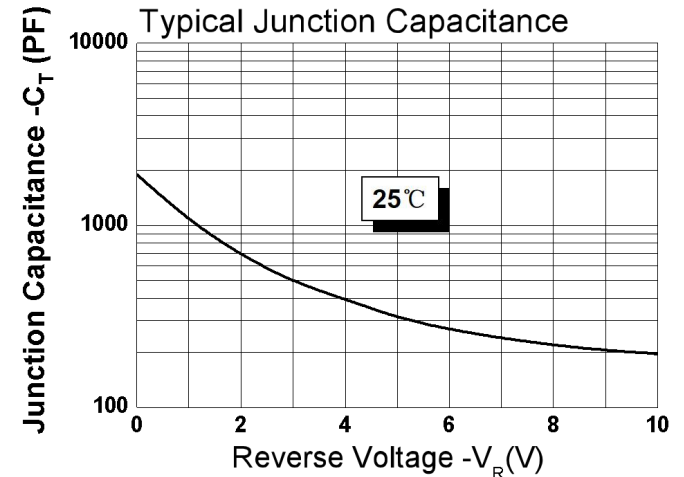
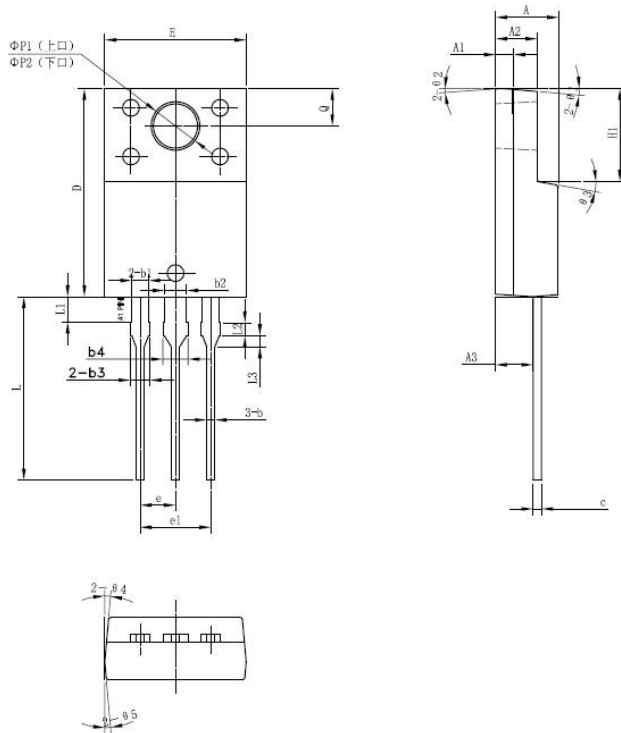


Figure 3
Typical Junction Capacitance

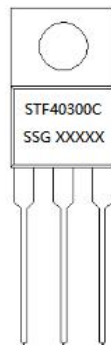


Mechanical Dimensions ITO-220AB



SYMBOL	Millimeters		
	MIN.	TYP.	MAX.
A	4.30	4.50	4.70
A1	1.10	1.30	1.50
A2	2.80	3.00	3.20
A3	2.50	2.70	2.90
b	0.50	0.60	0.75
b1	1.10	1.20	1.35
b2	1.50	1.60	1.75
b3	1.20	1.30	1.45
b4	1.60	1.70	1.85
c	0.50	0.60	0.75
D	14.80	15.00	15.20
E	9.96	10.16	10.36
e		2.55	
e1		5.10	
H1	6.50	6.70	6.90
L	12.70	13.20	13.70
L1	1.60	1.80	2.00
L2	0.80	1.00	1.20
L3	0.60	0.80	1.00
ΦP1(上口)	3.30	3.50	3.70
ΦP2(下口)	2.99	3.19	3.39
Q	2.50	2.70	2.90
θ1		5°	
θ2		4°	
θ3		10°	
θ4		5°	
θ5		5°	

Marking Diagram

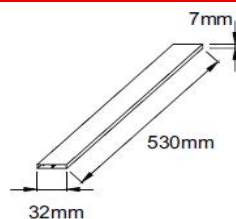


Where XXXXX is YYWWL

ST = Device Type
F = Package type
40 = Forward Current (40A)
300 = Reverse Voltage (300V)
C = Configuration
SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin
Epoxy resin UL94V-0

Tube Specification



Ordering Information

Device	Package	Shipping
STF40300C	ITO-220AB (Pb-Free)	50 pcs/ tube

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